

AES1A THRU AES1J

175mA. Super Fast Surface Mount Rectifiers



Voltage Range 50 to 600 Volts Current 175 mAmpere

SOD-323F

Features

- ♦ Glass passivated junction chip
- ♦ For surface mounted application
- ♦ Low profile package
- ♦ Built-in strain relief,
- ♦ Ideal for automated placement
- Superfast recovery time for high efficiency
- ♦ Glass passivated chip junction
- High temperature soldering:
 260°C/10 seconds at terminals
- Plastic material used carries Underwriters Laboratory Classification 94V-O

Mechanical Data

- ♦ Cases: Molded plastic♦ Terminals: Solder plated
- ♦ Polarity: Indicated by cathode band
- ♦ Packing: tape per E1A STD RS-481
- Weight: 0.01 gram

0.006(0.15) 0.008(0.2) 0.035(0.9)

Dimensions in inches and (millimeters)

0.031(0.8)

0.047(1.2)

Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	AES 1A	AES 1B	AES 1C	AES 1D	AES 1F	AES 1G	AES 1H	AES 1J	Units
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	50	100	150	200	300	400	500	600	V
Maximum RMS Voltage	V_{RMS}	35	70	105	140	210	280	350	420	V
Maximum DC Blocking Voltage	V_{DC}	50	100	150	200	300	400	500	600	V
Marking Code		EΑ	EB	EC	ED	EF	EG	EH	EJ	
Maximum Average Forward Rectified Current @ 85° @ 25°	I _(AV) I _(PEAK)	175 625								mA
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I _{FSM}	20								А
Maximum Instantaneous Forward Voltage IF=175mA @ 85℃ @ 25℃	V _F	1.25 1.45								V
Maximum DC Reverse Current @ $T_A = 25^{\circ}$ C at Rated DC Blocking Voltage	I _R	0.1								uA
Maximum Reverse Recovery Time (Note 1)	Trr	50								nS
Typical Junction Capacitance (Note 2)	Cj	5								pF
Maximum Thermal Resistance (Note 3)	$R \theta_{JA} \ R \theta_{JL}$	85 35								C /W
Operating Temperature Range	T_J	-40 to +85								Ç
Storage Temperature Range	Tstg	-40 to +85								C

Notes: 1. Reverse Recovery Test Conditions: IF=0.5A, IR=1.0A, IRR=0.25A

2. Measured at 1 MHz and Applied VR=4.0 Volts

3. P.C.B. Mounted on 0.2 x 0.2"(5.0 x 5.0mm) Copper Pad Area.